## NSN 5962-01-328-7217

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Between 0.875 inches and 0.925 inches

**Overall Height:** 

Between 0.265 inches and 0.360 inches

**Body Length:** 

Between 0.875 inches and 0.925 inches

**Body Width:** 

Between 0.280 inches and 0.310 inches

**Body Height:** 

Between 0.080 inches and 0.185 inches

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

**Features Provided:** 

High speed and high reliability and low current and bipolar

**Inclosure Material:** 

Ceramic

**Inclosure Configuration:** 

Dual-in-line

**Output Logic Form:** 

Transistor-transistor logic

**Input Circuit Pattern:** 

12 input

**Current Rating Per Characteristic:** 

250.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

**Terminal Surface Treatment:** 

Solder

**Voltage Rating And Type Per Characteristic:** 

-0.5 volts power source and 7.0 volts power source

**Capitance Rating Per Characteristic:** 

5.00 input picofarads and 8.00 output picofarads

**Time Rating Per Chacteristic:** 

70.00 nanoseconds af output megawatts

**Memory Device Type:** 

Prom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

18 printed circuit

Shelf Life:

N/a

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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